

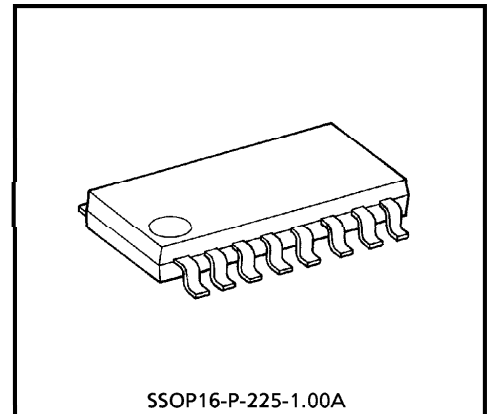
# TA8317F

## LED DRIVER FOR CAMERA

TA8317F is Multi Chip IC incorporates 6 low saturation discrete transistors which equipped bias resistor.  
This IC is suitable for a camera use LED drive applications.

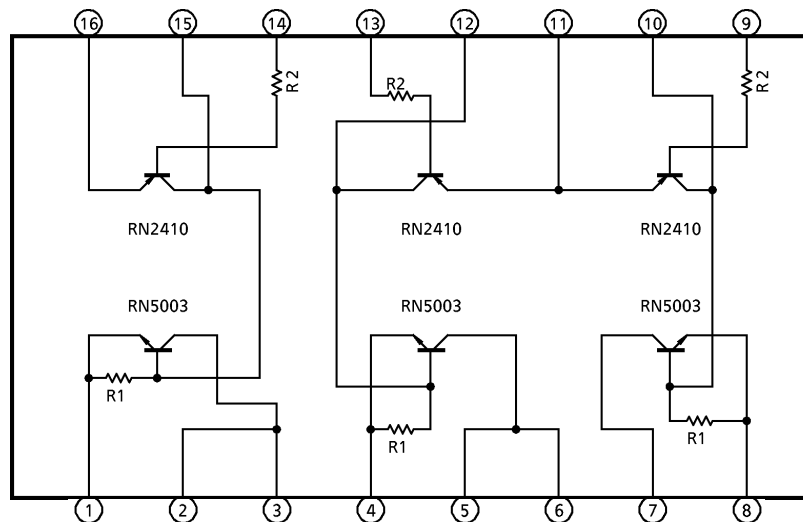
### FEATURES

- Suitable for LED drive circuit.
- Built-in Bias Resistor :  $R = 10k\Omega$
- Small package sealed : SSOP16
- Low saturation voltage



Weight : 0.14g (Typ.)

### BLOCK DIAGRAM



980910EBA2

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## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V <sub>CC</sub>	7.0	V
Breakdown Voltage	V <sub>CB0</sub>	10	V
	V <sub>CEO</sub>	10	V
	V <sub>EB0</sub>	5	V
Output Current (PNP / NPN)	I <sub>OUT</sub>	100 / 2	mA / A
Base Current	I <sub>B</sub>	0.4	A
Power Dissipation	P <sub>D</sub>	490	mW
Junction Temperature	T <sub>j</sub>	150	°C
Operating Temperature	T <sub>opr</sub>	- 20~60	°C
Storage Temperature	T <sub>stg</sub>	- 55~150	°C

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

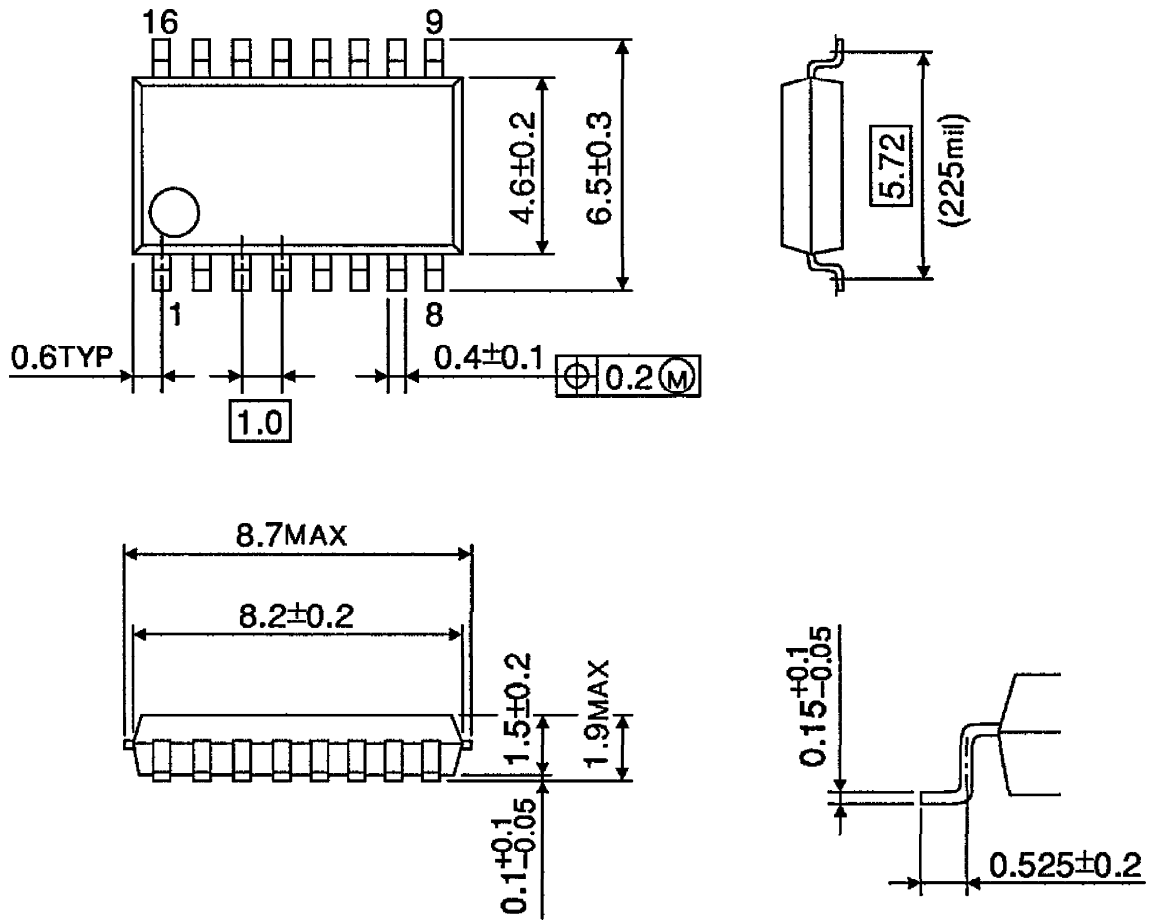
CHARACTERISTIC	SYMBOL	MEASURING Tr	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Gain	h <sub>FE</sub> 1	RN5003	—	V <sub>CE</sub> = 2V, I <sub>C</sub> = 0.5A	100	—	400	
	h <sub>FE</sub> 2	RN2410	—	V <sub>CE</sub> = 5V, I <sub>C</sub> = 1mA	120	—	400	
Saturation Voltage	V <sub>sat</sub> 1	RN5003	—	I <sub>C</sub> = 2A, I <sub>B</sub> = 0.05A	—	—	0.5	V
	V <sub>sat</sub> 2	RN2410	—	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	—	—	0.3	V
Transition Frequency	f <sub>T1</sub>	RN5003	—	V <sub>CE</sub> = 2V, I <sub>C</sub> = 0.5mA	—	—	120	MHz
	f <sub>T2</sub>	RN2410	—	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	—	—	200	MHz
Resistance Value	R <sub>1</sub>	RN5003	—		7	10	13	kΩ
	R <sub>2</sub>	RN2410	—		3.29	4.7	6.11	kΩ

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**OUTLINE DRAWING**  
SSOP16-P-225-1.00A

Unit : mm



Weight : 0.14g (Typ.)